

T-75-27-09

# TP5089 DTMF (TOUCH-TONE) Generator

## **General Description**

The TP5089 is a low threshold voltage, field-implanted, metal gate CMOS integrated circuit. It interfaces directly to a standard telephone keypad and generates all dual tone mul-ti-frequency pairs required in tone-dialing systems. The tone synthesizers are locked to an on-chip reference oscillator using an inexpensive 3.579545 MHz crystal for high tone accuracy. The crystal and an output load resistor are the only external components required for tone generation. A MUTE OUT logic signal, which changes state when any key is depressed, is also provided.

### **Features**

- 3.5V-10V operation when generating tones
- 2V operation of keyscan and MUTE logic
- Static sensing of key closures or logic inputs
- On-chip 3.579545 MHz crystal-controlled oscillator
- Output amplitudes proportional to supply voltage
- High group pre-emphasis
- Low harmonic distortion
- Open emitter-follower low-impedance output
- SINGLE TONE INHIBIT pin

### **Block Diagram**

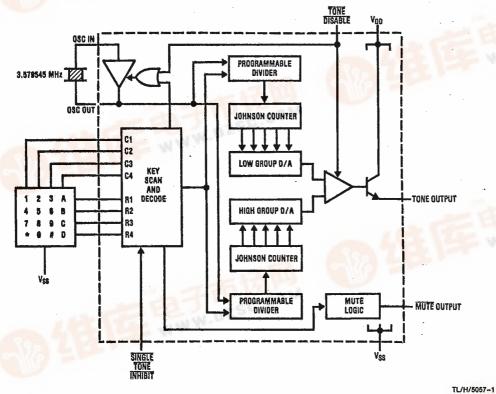


FIGURE 1





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**Absolute Maximum Ratings** 

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

**Operating Temperature** Storage Temperature Maximum Power Dissipation

-30°C to +60°C -55°C to + 150°C 500 mW

Supply Voltage (V<sub>DD</sub> - V<sub>SS</sub>) 15V Maximum Voltage at Any Pin  $V_{DD} + 0.3V$  to V<sub>SS</sub> - 0.3V

Electrical Characteristics Unless otherwise noted, limits printed in BOLD characters are guaranteed for VDD = 3.5V to 10V,  $T_A = 0^{\circ}$ C to  $+60^{\circ}$ C by correlation with 100% electrical testing at  $T_A = 25^{\circ}$ C. All other limits are assured by correlation with other production tests and/or product design and characterization.

31E D

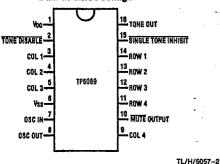
Parameter	Conditions	Min	Тур	Max	Units V
Minimum Supply Voltage for Keysense and MUTE Logic Functions		2			
Minimum Operating Voltage for generating tones		3,5	* 14F		٧
Operating Current - Idle - Generating Tones	Mute open R <sub>L</sub> = ∞ V <sub>DD</sub> = 3.5V	25 2.5	2 1.1		μA mA
Input Resistors COLUMN and ROW (Pull-Up) SINGLE TONE INHIBIT (Pull-Down) TONE DISABLE (Pull-Up)		25 120	50		kΩ kΩ
Input Low Level				0.2 V <sub>DD</sub>	٧
Input High Level		0.8 V <sub>DD</sub>			V
MUTE OUT Sink Current (COLUMN and ROW Active)	V <sub>DD</sub> = 3.5V V <sub>o</sub> = 0.5V	0.4	e* 1.1		mA
MUTE Out Leakage Current	$V_0 = V_{DD}$		1		μA
Output Amplitude Low Group	$R_L = 240 \Omega$ $V_{DD} = 3.5 V$	190	250	340	mVrms
	$R_L = 240\Omega$ $V_{DD} = 10V$	510	700	880	mVrms
Output Amplitude High Group	$R_{L} = 240\Omega$ $V_{DD} = 3.5V$	270	340	470	mVrms
	$R_{L} = 240\Omega$ $V_{DD} = 10V$	735	955	1265	mVrms
Mean Output DC Offset	V <sub>DD</sub> = 3.5V V <sub>DD</sub> = 10V	1	1,3- 4,6		V V
High Group Pre-Emphasis		2.2	2.7	3,2	dB
Dual Tone/Total Harmonic Distortion Ratio	V <sub>DD</sub> = 4V, R <sub>L</sub> = 240Ω 1 MHz Bandwidth	-22	-23		dB
Start-Up Time (to 90% Amplitude)			3	5	mS

Note 1: RL is the external load resistor connected from TONE OUT to Vss.

Note 2: Crystal specification: Parallel resonant 3.579545 MHz,  $R_S \le 150~\Omega$ , L = 100 mH,  $C_O = 5$  pF,  $C_I = 0.02$  pF.

## **Connection Diagram**

#### Dual-In-Line Package



**Top View** 

Order Number TP5089N or TP5089WM See NS Package N16A and M16B

#### **Pin Descriptions**

Symbol

Description

 $V_{DD}$ 

Vss

This is the positive voltage supply to the device, referenced to Vss. The collector of the TONE OUT transistor is connected to this pin. This is the negative voltage supply. All voltages are

OSC IN, OSC OUT

referenced to this pin. All tone generation timing is derived from the on-chip oscillator circuit. A low cost 3.579545 MHz A-cut crystal (NTSC TV color-burst) is needed between pins 7 and 8. Load capacitors and a feedback resistor are included on-chip for good start-up and stability. The oscillator stops when column inputs are sensed with no valid input having been detected. The oscillator is also stopped when the TONE DISABLE input is pulled to logic low.

Row and Column Inputs

When no key is pushed, pull-up resistors are active on row and column inputs. A key closure is recognized when a single row and a single column are connected to V<sub>SS</sub>, which starts the oscillator and initiates tone generation. Negative-true logic signals simulating key closures can also be used

The TONE DISABLE input has

an internal pull-up resistor.

logic high, the normal tone output mode will occur. When

When this input is open or at

TONE DISABLE input is at logic

low, the device will be in the Inactive mode, TONE OUT will be at an open circuit state,

**TONE DISABLE** 

Input

**Symbol MUTE** Output

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SINGLE TONE INHIBIT Input

TONE OUT

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Description

The MUTE output is an opendrain N-channel device that sinks current to VSS with any key input and is open when no key input is sensed. The MUTE output will switch regardless of the state of the SINGLE TONE **INHIBIT** input.

The SINGLE TONE INHIBIT input is used to inhibit the generation of other than valid tone pairs due to multiple rowcolumn closures. It has a pulldown resistor to Vss, and when left open or tied to Vss any input condition that would normally result in a single tone will now result in no tone, with all other functions operating normally. When tied to VDD, single or dual tones may be generated, see Table II.

This output is the open emitter of an NPN transistor, the collector of which is connected to V<sub>DD</sub>. When an external load resistor is connected from TONE OUT to VSS, the output voltage on this pin is the sum of the high and low group sinewaves superimposed on a DC offset. When not generating tones, this output transistor is turned OFF to minimize the device idle current.

Adjustment of the emitter load resistor results in variation of the mean DC current during tone generation, the sinewave signal current through the output transistor, and the output distortion. Increasing values of load resistance decrease both the signal current and distortion.

### **Functional Description**

With no key inputs to the device the oscillator is inhibited, the output transistor is pulled OFF and device current consumption is reduced to a minimum. Key closures are sensed statically. Any key closure activates the MUTE output, starts the oscillator and sets the high group and low group programmable counters to the appropriate divide ratio. These counters sequence two ratioed-capacitor D/A converters through a series of 28 equal duration steps per sine-wave cycle. The two tones are summed by a mixer amplifier, with pre-emphasis applied to the high group tone. The output is an NPN emitter-follower requiring the addition of an external load resistor to Vss. This resistor facilitates adjustment of the signal current flowing from VDD through the output tran-

The amplitude of the output tones is directly proportional to the device supply voltage.



## Functional Description (Continued)

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**TABLE I. Output Frequency Accuracy** 

	(MDIE II Garbart reducine) received						
Tone	Valid	Standard	Tone Output	% Deviation			
Group	Input	DTMF (Hz)	Frequency	from Standard			
Low	R1	697	694.8	0.32			
Group	R2	770	770.1	+0.02			
fL	R3	852	852.4	+0.03			
High	R4	941	940.0	-0.11			
	C1	1209	1206.0	-0.24			
Group	C2	1336	1331.7	-0.32			
fH	C3	1477	1486.5	+ 0.64			
	C4	1633	1639.0	+ 0.37			

TABLE II. Functional Truth Table

SINGLE TONE INHIBIT	TONE DISABLE	ROW	COLUMN	TONE OUT		MUTE
		ROW		Low	High	
×	0	O/C	O/C	٥٧	٥٧	O/C
X	X	0/0	0/0	ov	07	O/C
X	0	One	One	Vos	Vos	0
X	1	One	One	fL	fH	0
1	1	2 or More	One	_	fH	0
1	1	One	2 or More	f <sub>L</sub>	_	Q
1	1	2 or More	2 or More	Vos	Vos	0
0	1	2 or More	One	Vos	Vos	0
0	1	One	2 or More	Vos	Vos	0
0	1	2 or More	2 or More	Vos	Vos	0

Note 1: X is don't care state.

Note 2: Vos is the output offset voltage.

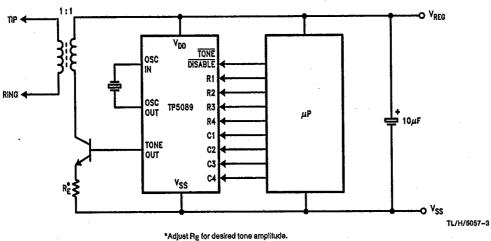


FIGURE 2. Typical Application